NSN 5961-01-312-1186

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-312-1186 **Inclosure Material:** Glass **Overall Length:** 0.200 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.090 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 40.0 reverse voltage, peak **Current Rating Per Characteristic:** 2.00 amperes forward current, average preset **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No